





CMDSH-3 SCHOTTKY BARRIER DIODE



Features

CMDSH-3 type is a silicon Schottky diode, manufactured in a surface mount package, designed for fast switching applications requiring a low forward voltage drop.

Schematic & Pin Configuration



Mechanical Characteristics

• Case: SOD-323, Molded plastic

• Terminals: Plated Leads Solderable per MIL-STD-202,

Method 208

Polarity: Cathode Band
Weight: 0.04 grams(approx)

Maximum Ratings @T_A=25°C unless otherwise specified

Characteristic	Symbol	Value	Units
Peak Reverse Voltage	V_{RRM}	30	V
Average Forward Current	lo	100	mA
Power Dissipation	P _D	250	mW
Power Dissipation(T _L = 25°C)	P _D	833	mW
Peak Forward Surge Current (tp=8.3ms)	IFSM	750	mA
Operating Junction Temperature Range	TJ	-65 to +150	°C
Storage Temperature Range	T _{STG}	-65 to +150	°C
Thermal Resistance	R _{⊝JA}	500	°C/W
Thermal Resistance	R _{⊝JL}	150	°C/W

Note: 1. Valid provided that terminals are kept at ambient temperature.





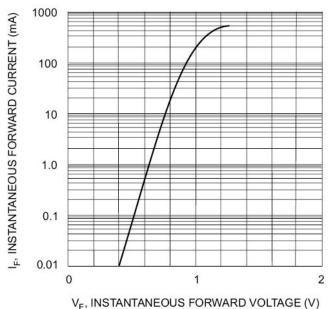


Electrical Characteristics @TA=25°C unless otherwise specified

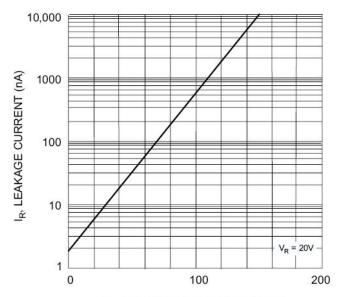
Characteristics	Symbol	Condition	Min	Тур.	Max.	Units
Forward Voltage Drop*	V _F	$@I_F = 50mA, T_A = 25^{\circ}C$	-	-	0.55	V
		$@I_F = 100 \text{mA}, T_A = 25^{\circ}\text{C}$	-	-	0.80	
Reverse Recovery Voltage*	V_{BR}	@I _F = 100uA	30	-	-	V
Reverse Current*	I _R	@V _R = 25V, T _J = 25 °C	-	-	10	uA
Typical Junction Capacitance	Cj	@V _R =10.0 V, Tc=25°C, f _{SIG} = 1MHz	-	7.0	-	pF

^{*} Pulse width < 300 µs, duty cycle < 2%

Ratings and Characteristics Curves



INSTANTANEOUS FORWARD VOLTAGE (V)
 Fig. 1 Forward Characteristics



 $\label{eq:tj} \textbf{T}_{j}, \, \text{JUNCTION TEMPERATURE (°C)} \\ \text{Fig. 2 Leakage Current vs Junction Temperature}$

[•] China - Germany - Korea - Singapore - United States •

[•] http://www.smc-diodes.com - sales@ smc-diodes.com •







Ordering Information

Device	Package	Shipping
CMDSH-3	SOD-323 (Pb-Free)	3000pcs / reel

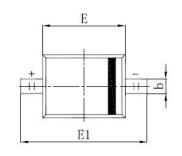
For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

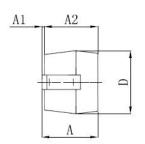
Marking Diagram

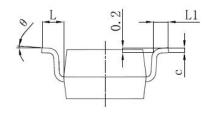


S1 = Marking Code

Mechanical Dimensions SOD-323

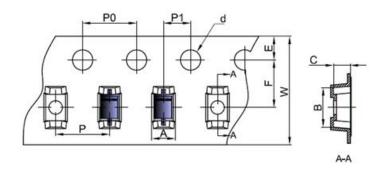






OVALDOL	Millimeters		Inches		
SYMBOL	MIN.	MAX.	MIN.	MAX.	
Α	-	1.000	-	0.039	
A1	0.000	0.100	0.000	0.004	
A2	0.800	0.900	0.031	0.035	
b	0.250	0.350	0.010	0.014	
С	0.080	0.150	0.003	0.006	
D	1.200	1.400	0.047	0.055	
Е	1.600	1.800	0.063	0.071	
E1	2.500	2.700	0.098	0.106	
L	0.475 REF.		0.019 REF.		
L1	0.250	0.400	0.010	0.016	
θ	0°	8°	0°	8°	

Carrier Tape Specification SOD-323



SYMB	Millimeters		
OL	Min.	Max.	
В	2.85	2.95	
С	1.20	1.30	
d	1.40	1.60	
E	1.65	1.85	
F	3.40	3.60	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
W	7.90	8.30	

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